MDD26-08N1B

## Standard Rectifier Module

## Phase leg

## Part number

## MDD26-08N1B

| $\mathrm{V}_{\mathrm{RRM}}=2 \mathrm{x} 800 \mathrm{~V}$ |  |
| :--- | :--- |
| $\mathrm{I}_{\mathrm{FAV}}=$ | 36 A |
| $\mathrm{~V}_{\mathrm{F}}$ | $=1.05 \mathrm{~V}$ |



Backside: isolated



## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current


## Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling


## Disclaimer Notice

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| Rectifier |  |  |  | Ratings |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Definition | Conditions |  | min. | typ. | max. | Unit |
| $\mathrm{V}_{\text {RSM }}$ | max. non-repetitive reverse blocking voltage |  | $\mathrm{T}_{\mathrm{v} \mathrm{J}}=25^{\circ} \mathrm{C}$ |  |  | 900 | V |
| $\mathrm{V}_{\text {RRM }}$ | max. repetitive reverse blocking voltage |  | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 800 | V |
| $\mathrm{I}_{\text {R }}$ | reverse current | $\mathrm{V}_{\mathrm{R}}=800 \mathrm{~V}$ | $\mathrm{T}_{\mathrm{v} J}=25^{\circ} \mathrm{C}$ |  |  | 100 |  |
|  |  | $\mathrm{V}_{\mathrm{R}}=800 \mathrm{~V}$ | $\mathrm{T}_{\mathrm{vs}}=150^{\circ} \mathrm{C}$ |  |  | 1.5 | mA |
| $\overline{V_{F}}$ | forward voltage drop | $\mathrm{I}_{\mathrm{F}}=40 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 1.13 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=80 \mathrm{~A}$ |  |  |  | 1.38 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=40 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{v} j}=125^{\circ} \mathrm{C}$ |  |  | 1.05 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=80 \mathrm{~A}$ |  |  |  | 1.27 | V |
| $\mathrm{I}_{\text {fav }}$ | average forward current | $\mathrm{T}_{\mathrm{C}}=100^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{v},}=150^{\circ} \mathrm{C}$ |  |  | 36 | A |
| $\mathrm{I}_{\text {F(RMS) }}$ | RMS forward current | $180^{\circ}$ sine |  |  |  | 60 | A |
| $\mathrm{V}_{\text {F0 }}$ | $\left.\begin{array}{l} \text { threshold voltage } \\ \text { slope resistance } \end{array}\right\} \text { for power loss calculation only }$ |  | $\mathrm{T}_{\mathrm{v},}=150^{\circ} \mathrm{C}$ |  |  | 0.80 | V |
| $\mathrm{r}_{\mathrm{F}}$ |  |  | 6.1 |  |  | $\mathrm{m} \Omega$ |
| $\mathbf{R}_{\text {thJc }}$ | thermal resistance junction to case |  |  |  |  |  | 1 | K/W |
| $\mathbf{R}_{\text {thCH }}$ | thermal resistance case to heatsink |  |  |  | 0.2 |  | K/W |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  |  | 125 | W |
| $\mathrm{I}_{\text {FSM }}$ | max. forward surge current | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{vs}}=45^{\circ} \mathrm{C}$ |  |  | 650 | A |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $V_{R}=0 V$ |  |  | 700 | A |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$; 50 Hz ), sine | $\mathrm{T}_{\mathrm{v} s}=150^{\circ} \mathrm{C}$ |  |  | 555 | A |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 595 | A |
| 12t | value for fusing | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{v} j}=45^{\circ} \mathrm{C}$ |  |  | 2.12 | $\mathrm{kA}^{2} \mathrm{~s}$ |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 2.04 | $\mathrm{kA}^{2} \mathrm{~s}$ |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{v} ~}=150^{\circ} \mathrm{C}$ |  |  | 1.54 | $\mathrm{kA}^{2} \mathrm{~S}$ |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 1.48 | $\mathrm{kA}^{2} \mathrm{~s}$ |
| C | junction capacitance | $\mathrm{V}_{\mathrm{R}}=400 \mathrm{~V} ; \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  | 27 |  | pF |


| Package | TO-240AA |  |  | Ratings |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Definition Conditions |  |  | min. | typ. | max. | Unit |
| $\mathrm{I}_{\text {RMS }}$ | RMS current per terminal |  |  |  |  | 200 | A |
| $\mathrm{T}_{\mathrm{v}}$ | virtual junction temperature |  |  | -40 |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {op }}$ | operation temperature |  |  | -40 |  | 125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  |  | -40 |  | 125 | ${ }^{\circ} \mathrm{C}$ |
| Weight |  |  |  |  | 76 |  | g |
| $\begin{aligned} & \mathbf{M}_{\mathbf{D}} \\ & \mathbf{M}_{\mathrm{T}} \end{aligned}$ | mounting torque terminal torque |  |  | $\begin{aligned} & 2.5 \\ & 2.5 \end{aligned}$ |  | 4 | Nm Nm |
| $\mathbf{d}_{\text {spp/App }}$ <br> $\mathbf{d}_{\text {Spb/Apb }}$ | creepage distance on surface / striking distance through air | terminal to terminal terminal to backside | $\begin{aligned} & 13.0 \\ & 16.0 \end{aligned}$ | $\begin{array}{r} 9.7 \\ 16.0 \end{array}$ |  |  | $\begin{aligned} & \mathrm{mm} \\ & \mathrm{~mm} \end{aligned}$ |
| $\mathrm{V}_{\text {ISOL }}$ | isolation voltage $\begin{aligned} & \text { t }=1 \text { second } \\ & \\ & t=1 \text { minute }\end{aligned}$ | $50 / 60 \mathrm{~Hz}, \mathrm{RMS}$; lisol $\leq 1 \mathrm{~mA}$ |  | $\begin{aligned} & 4800 \\ & 4000 \end{aligned}$ |  |  | V V |



Part Number Lot\#

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Standard | MDD26-08N1B | MDD26-08N1B | Box | 36 | 453013 |


| Similar Part | Package | Voltage class |
| :--- | :--- | :---: |
| MDD26-12N1B | TO-240AA | 1200 |
| MDD26-14N1B | TO-240AA | 1400 |
| MDD26-16N1B | TO-240AA | 1600 |
| MDD26-18N1B | TO-240AA | 1800 |

## Equivalent Circuits for Simulation *on die level $\quad \mathrm{T}_{\mathrm{vJ}}=150^{\circ} \mathrm{C}$

| $\mathrm{I} \rightarrow \mathrm{~V}_{0}-\mathrm{R}_{0}$ |  | Rectifier |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{0 \text { max }}$ | threshold voltage | 0.8 | V |
| $\mathbf{R}_{0 \text { max }}$ | slope resistance * | 4.9 | $\mathrm{m} \Omega$ |

## Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c"


## Rectifier



Fig. 1 Surge overload current $\mathrm{I}_{\text {TsM }}$ : Crest value, t : duration


Fig. $2 I^{2}$ t versus time ( $1-10 \mathrm{~ms}$ )


Fig. 3 Max. forward current at case temperature


Fig. 4 Power dissipation versus onstate current \& ambient temperature (per diode)


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current ${ }^{L}$ and ambient temperature; $R=$ resistive load, $L=$ inductive load

## Rectifier



Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature


Fig. 7 Transient thermal impedance junction to case (per diode)


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)
$\mathrm{R}_{\mathrm{th} \mathrm{Jc}}$ for various conduction angles d :

| $\mathbf{d}$ | $\mathbf{R}_{\text {thuc }}[K / W]$ |
| :---: | :---: |
| DC | 1.00 |
| $180^{\circ}$ | 1.02 |
| $120^{\circ}$ | 1.04 |
| $60^{\circ}$ | 1.07 |
| $30^{\circ}$ | 1.10 |

Constants for $\mathrm{Z}_{\mathrm{thJC}}$ calculation:

| $\mathbf{i}$ | $\mathbf{R}_{\mathrm{thi}}[\mathbf{K} / \mathbf{W}]$ | $\mathbf{t}_{\mathbf{i}}[\mathbf{s}]$ |
| :---: | :---: | :---: |
| 1 | 0.01 | 0.0012 |
| 2 | 0.03 | 0.0950 |
| 3 | 0.96 | 0.4550 |

$\mathrm{R}_{\mathrm{tt} \mathrm{JK}}$ for various conduction angles d :

| $\mathbf{d}$ | $\mathbf{R}_{\text {thJK }}[K / W]$ |
| ---: | :---: |
| DC | 1.20 |
| $180^{\circ}$ | 1.22 |
| $120^{\circ}$ | 1.24 |
| $60^{\circ}$ | 1.27 |
| $30^{\circ}$ | 1.30 |

Constants for $\mathrm{Z}_{\mathrm{t}, \mathrm{Jk}}$ calculation:

| $\mathbf{i}$ | $\mathbf{R}_{\mathbf{t h}}[\mathbf{K} / \mathbf{W}]$ | $\mathbf{t}_{\mathbf{i}}[\mathbf{s}]$ |
| :---: | :---: | :---: |
| 1 | 0.01 | 0.0012 |
| 2 | 0.03 | 0.0950 |
| 3 | 0.96 | 0.4550 |
| 4 | 0.20 | 0.4950 |

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